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Amendment and/or Response  
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**Amendments to the Claims:**

A clean version of the entire set of pending claims (including amendments to the claims, if any) is submitted herewith per 37 CFR 1.121(c)(3). This listing of claims will replace all prior versions, and listings, of claims in the application.

**Listing of Claims:**

1. (Original) A method of fabricating a device, the method comprising:  
providing a layer structure;  
forming a first patterned layer onto a surface of said layer structure so as to mask a first region of said surface;  
forming a second patterned layer onto said surface layer of said layer structure so as to mask a second region of said surface and to leave unmasked a third region of said surface;  
etching said layer structure in said third region; and  
either removing said second patterned layer and etching said layer structure in said second region or  
removing said first patterned layer and etching said layer structure in said first region, wherein at least one of said first or second patterned layers is formed by printing.
2. (Original) A method according to claim 1, wherein both of the first and second patterned layers are formed by printing.
3. (Original) A method according to claim 2, wherein said printing of said second patterned layer comprises:  
overlapping said second patterned layer with at least a portion of said first patterned layer.

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4. (Previously Presented) A method according to claim 2, wherein said printing of said second patterned layer occurs substantially immediately following the printing of the first layer.

5. (Previously Presented) A method according to claim 2, comprising:  
printing said first patterned layer having a first thickness and  
printing said second patterned layer having a second, different thickness.

6. (Previously Presented) A method according to claim 2, comprising:  
using a first ink for printing said first patterned layer and  
using a second ink for printing said second patterned layer.

7. (Original) A method according to claim 6, wherein said first and second inks are different.

8. (Previously Presented) A method according to claim 6, wherein said first and second inks are diluted to different concentrations.

9. (Previously Presented) A method of fabricating a thin-film transistor according to claim 1.

10. (Previously Presented) A method according to claim 1, further comprising:  
providing a substrate;  
providing a patterned conductive gate region on said substrate;  
providing a dielectric layer overlying said substrate and said patterned conductive gate region;  
providing a first semiconductor layer overlying said dielectric layer;  
providing a second semiconductor layer overlying said first semiconductor layer;  
providing a metalisation layer overlying said second semiconductor layer.

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11. (Previously Presented) A method according to claim 2, when said printing of said first layer includes defining regions for forming source and drain terminals.

12. (Previously Presented) Apparatus configured to perform the method according to claim 1.

13. (Currently Amended) ~~Apparatus~~ An apparatus for fabricating a thin-film transistor, comprising:

printing means, said printing means configured to print a first patterned layer on a layer structure and a second, different patterned layer on a layer structure;

etching means, said etching means configured to etch said layer structure;  
and

removing means, configured either to remove said first patterned layer and to leave at least part of said second patterned layer, or to remove said second patterned layer and to leave at least part of said first patterned layer.

14. (New) A method according to claim 3, wherein said printing of said second patterned layer occurs substantially immediately following the printing of the first layer.

15. (New) A method according to claim 3, comprising:

printing said first patterned layer having a first thickness; and

printing said second patterned layer having a second, different thickness.

16. (New) A method according to claim 4, comprising:

printing said first patterned layer having a first thickness; and

printing said second patterned layer having a second, different thickness.

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17. (New) A method according to claim 3, comprising:  
using a first ink for printing said first patterned layer; and  
using a second ink for printing said second patterned layer.

18. (New) A method according to claim 4, comprising:  
using a first ink for printing said first patterned layer; and  
using a second ink for printing said second patterned layer.

19. (New) A method according to claim 5, comprising:  
using a first ink for printing said first patterned layer; and  
using a second ink for printing said second patterned layer.

20. (New) A method according to claim 7, wherein said first and second inks  
are diluted to different concentrations.

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